
	<h2 style="color: #E67E22;">NVMFS5885NLWFT1G</h2>
	<p>Hersteller-Teilenummer: NVMFS5885NLWFT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 39A SO8FL</p> <hr/> <p>Datenblätter:  NVMFS5885NLWFT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

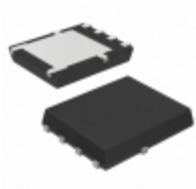
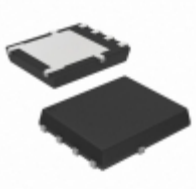
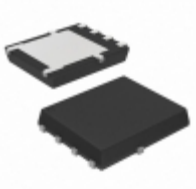
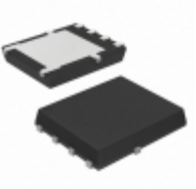
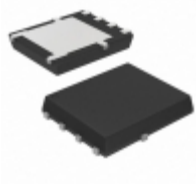
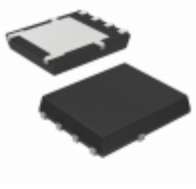
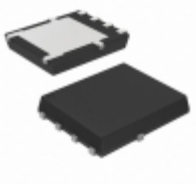
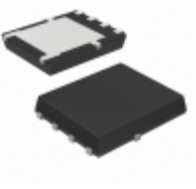
Spezifikationen

Teilenummer	NVMFS5885NLWFT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 39A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2.5V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	15 mOhm @ 15A, 10V
Verlustleistung (max)	3.7W (Ta), 54W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1340pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	21nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10.2A (Ta)

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RFQ NVMFS5885NLWFT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMFS5885NLT3G ON Semiconductor MOSFET N-CH 60V 39A SO8FL</p>	 <p>NVMFS5A140PLZWFT1G AMI Semiconductor / ON Semiconductor -40V4.2MOHMSINGLE</p>	 <p>NVMFS5844NLWFT3G ON Semiconductor MOSFET N-CH 60V 61A SO8FL</p>	 <p>NVMFS5844NLWFT1G ON Semiconductor MOSFET N-CH 60V 61A SO8FL</p>
 <p>NVMFS5844NLT3G ON Semiconductor MOSFET N-CH 60V 8SOIC</p>	 <p>NVMFS5A140PLZT3G AMI Semiconductor / ON Semiconductor -40V4.2MOHMSINGLE</p>	 <p>NVMFS5A140PLZWFT3G AMI Semiconductor / ON Semiconductor -40V4.2MOHMSINGLE</p>	 <p>NVMFS5885NLT1G ON Semiconductor MOSFET N-CH 60V 39A SO8FL</p>

Verwandtes Hot-Keyword

Mehr

NVMFS5885NLWFT1G AMI Semiconductor / ON Semiconductor	NVMFS5885NLWFT1G Datenblatt	NVMFS5885NLWFT1G-Datenblätter	NVMFS5885NLWFT1G PDF	AMI Semiconductor / ON Semiconductor NVMFS5885NLWFT1G
NVMFS5885NLWFT1G Electronic	NVMFS5885NLWFT1G-Komponenten	NVMFS5885NLWFT1G-Verteiler	NVMFS5885NLWFT1G-Bild	NVMFS5885NLWFT1G-Teil
NVMFS5885NLWFT1G Preis	NVMFS5885NLWFT1G Hersteller	NVMFS5885NLWFT1G Bild	NVMFS5885NLWFT1G Aktie	NVMFS5885NLWFT1G Inventar
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